Silicon NPN Epitaxial

HITACHI

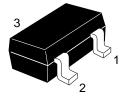
ADE-208-1076 (Z) 1st. Edition Mar. 2001

Application

- UHF/VHF frequency converter
- Local oscillator

Outline

MPAK



- 1. Emitter
- 2. Base
- 3. Collector

Note: Marking is "TC".



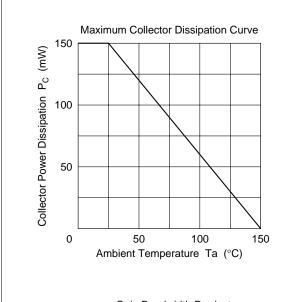
Absolute Maximum Ratings ($Ta = 25^{\circ}C$)

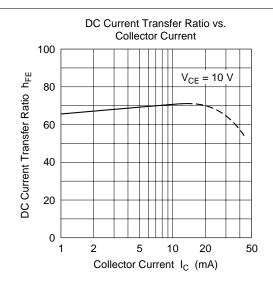
Item	Symbol	Ratings	Unit
Collector to base voltage	V_{CBO}	30	V
Collector to emitter voltage	V _{CEO}	20	V
Emitter to base voltage	V_{EBO}	3	V
Collector current	I _c	50	mA
Collector power dissipation	P _c	150	mW
Junction temperature	Tj	150	°C
Storage temperature	Tstg	-55 to +150	°C

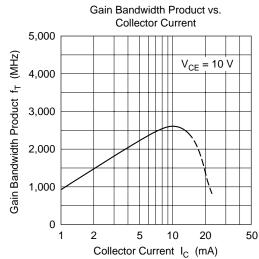
Electrical Characteristics ($Ta = 25^{\circ}C$)

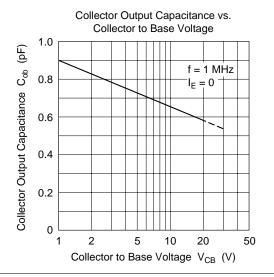
Item	Symbol	Min	Тур	Max	Unit	Test conditions
Collector to base breakdown voltage	$V_{(BR)CBO}$	30	_	_	V	$I_{C} = 10 \ \mu A, \ I_{E} = 0$
Collector to emitter breakdown voltage	$V_{(BR)CEO}$	20	_	_	V	$I_{C} = 1 \text{ mA}, R_{BE} = \infty$
Emitter to base breakdown voltage	$V_{(BR)EBO}$	3	_	_	V	$I_E = 10 \ \mu A, \ I_C = 0$
Collector cutoff current	I _{CBO}	_	_	500	nA	$V_{CB} = 15 \text{ V}, I_{C} = 0$
Collector to emitter saturation voltage	$V_{\text{CE}(\text{sat})}$	_	_	0.7	V	$I_C = 10 \text{ mA}, I_B = 5 \text{ mA}$
DC current transfer ratio	h _{FE}	30	_	200		$V_{CE} = 10 \text{ V}, I_{C} = 5 \text{ mA}$
Collector output capacitance	Cob	_	_	1.0	pF	$V_{CB} = 10 \text{ V}, I_{E} = 0, f = 1 \text{ MHz}$
Gain bandwidth product	f⊤	1400	2200	_	MHz	$V_{CE} = 10 \text{ V}, I_{C} = 5 \text{ mA}$
Conversion gain	CG ₁	_	22.5	_	dB	$V_{CC} = 12 \text{ V}, I_{C} = 2 \text{ mA},$ f = 200 MHz, $f_{OSC} = 230 \text{ MHz (0dBm)}$
	CG ₂	_	10	_	dB	V_{cc} = 12 V, I_c = 2 mA, f = 900 MHz, f_{osc} = 930 MHz (0dBm), f_{out} = 30 MHz
Noise figure	NF	_	4.0	_	dB	$V_{CC} = 12 \text{ V}, I_{C} = 2 \text{ mA},$ f = 200 MHz, $f_{OSC} = 230 \text{ MHz (0dBm)}$
Oscillating output voltage	V _{osc1}		300		mV	$V_{CC} = 12 \text{ V}, I_C = 7 \text{ mA},$ $f_{OSC} = 300 \text{ MHz}$
	V _{OSC2}	_	200	_	mV	$V_{CC} = 12 \text{ V}, I_C = 7 \text{ mA},$ $f_{OSC} = 930 \text{ MHz}$

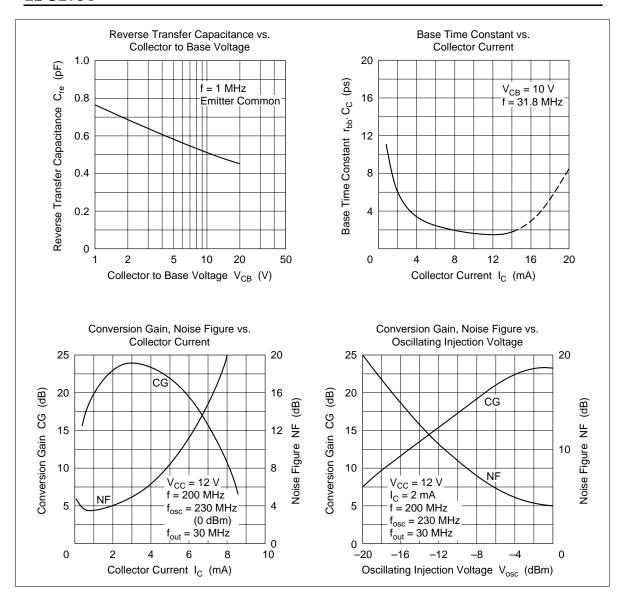
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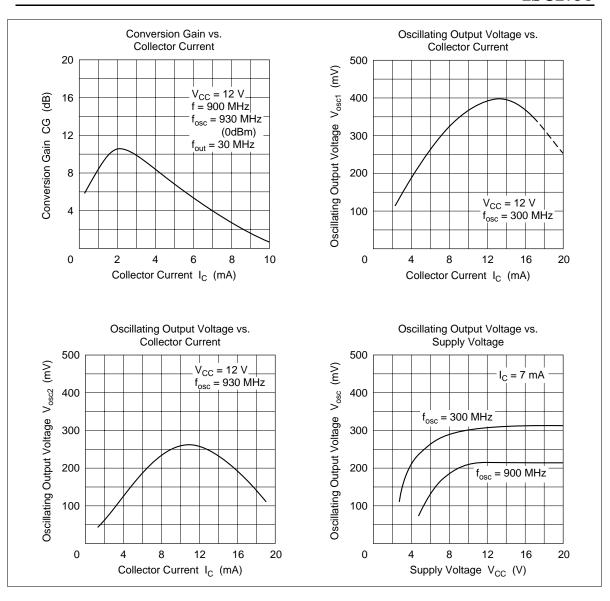


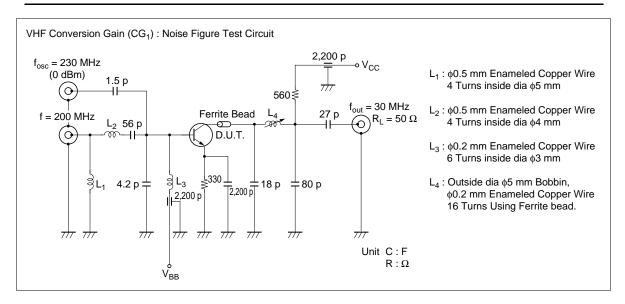




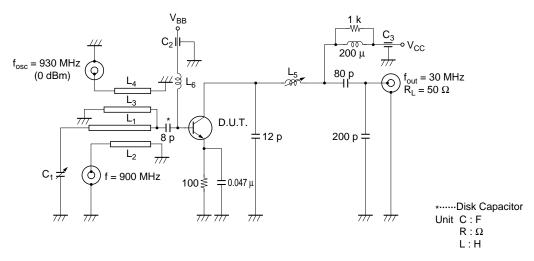


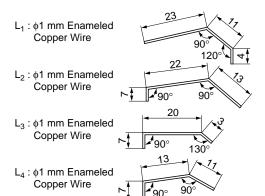










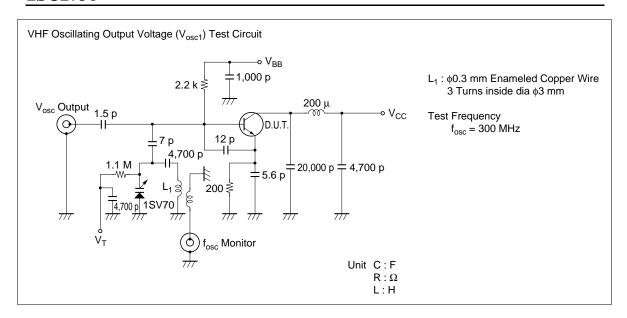


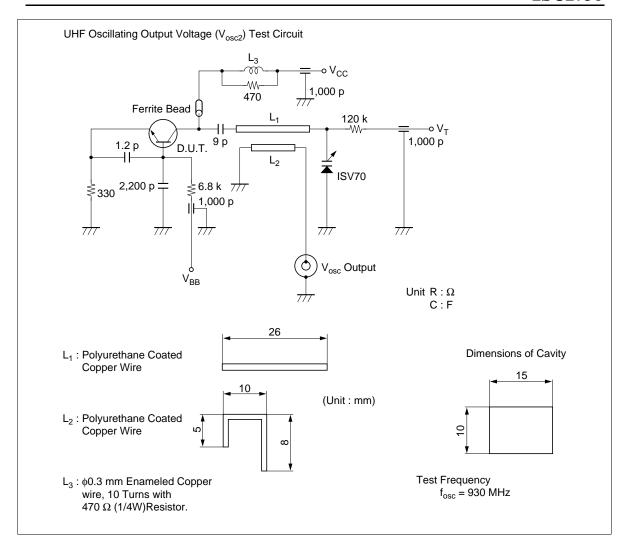
 L_5 : Bobbin $\phi 5$ mm inside dia, $\phi 0.2$ mm Enameled Copper Wire 20 Turns

 L_6 : $\phi 0.5$ mm Enameled Copper Wire 1 Turn inside dia $\phi 6$ mm

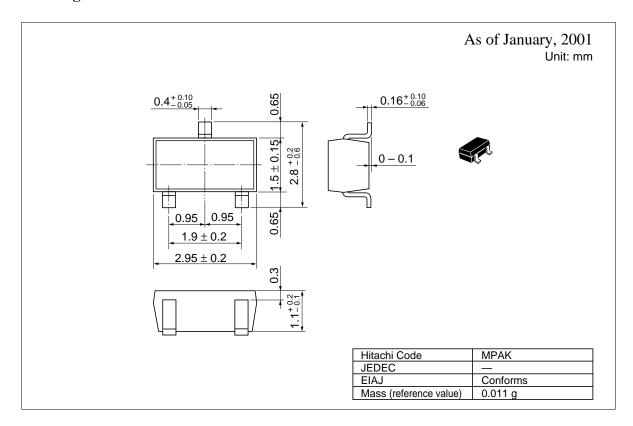
 C_1 : 20 pF max Air Trimmer Condenser

C2, C3: 1000 pF Air Core Capacitor





Package Dimensions



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